

EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole) and (terminal near electrode near outside near display)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 09:34
S1	2	"20020130983"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:04
S2	2	"5851918".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:05
S3	2	"5742074".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:06
S4	2	"6587160".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:07

S5	2	"5742074".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:10
S6	2	"5492074".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:11
S7	2	"5492582".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:11
S8	2	"6016174".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:13
S9	42	(349/43,42,139,147,158,138,122,149,150,151,152.cds.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and passivation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:30
S10	1	(349/43,42,139,147,158,138,122,149,150,151,152.cds.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and passivation and exfoliation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:32

S11	0	((349/43,42,139,147,158,138,122,149,150,151,152.cds.) and ((tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:33
S12	1	((tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:34
S13	0	((tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near (beneath or under) near (electrode or metallic or metal)) and passivation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:35
S14	2	((tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (first near (metal or metallic) near line) and (second near (metal or metallic) near line)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:36
S15	57	((tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (terminal near electrode)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:37
S16	0	((tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and ((terminal near electrode) near extend near (metal or metallic))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:38

S17	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near interposed near (conductive or electric))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:39
S18	790	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:39
S19	34	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole) and (terminal near electrode)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; BM_TDB	OR	OFF	2010/09/21 08:40

EAST Search History (Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole) and (terminal near electrode near outside near display)	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L3	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near interposed near (conductive or electric))	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L4	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near interposed near (conductive or electric))	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L5	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L6	0	(349/43,42,139,147,158,138,122,149,150,151,152.cds.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) near between near (electrode or metallic or metal)) and passivation	USPAT; UPAD	OR	OFF	2010/09/21 09:35

L7	0	((tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near (beneath or under) near (electrode or metallic or metal)) and passivation	USPAT; UPAD	OR	OFF	2010/09/21 09:35
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